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View Online at https://aerobasegroup.com/nsn/5962-01-382-1566 **Body Length:** Between 0.990 inches and 1.110 inches **Body Width:** Between 0.990 inches and 1.110 inches **Body Height:** Between 0.078 inches and 0.098 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Pacer dawn **Features Provided:** Burn in, mil-std-883, class b and electrostatic sensitive and high performance and tested to mil-std-883 **Inclosure Material:** Ceramic **Inclosure Configuration:** Pin grid array **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Criticality Code Justification:** Feat **Product Name:** Microcircuit high performance, microcontrollers, cmos Voltage Rating And Type Per Characteristic: 0.5 volts total and 0.7 volts total **Memory Device Type:** Pal **Special Features:** Esd **Precious Material And Location:** Terminal leads, lid, ring pads gold **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 34 pin Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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